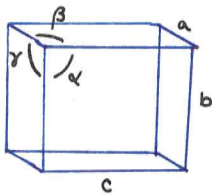


There are seven types of

UNIT CELLS

	$a \neq b \neq c$	$a = b \neq c$	$a = b = c$
$\alpha = \beta = \gamma$	ORTHO-RHOMBIC	TETRA-GONAL	CUBIC + TRIGONAL ($\frac{\sqrt{3}}{2}$)
$\alpha = \beta \neq \gamma$	MONOCLINIC	HEXA-GONAL	$\emptyset$
$\alpha \neq \beta \neq \gamma$	TRICLINIC	$\emptyset$	$\emptyset$

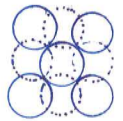
wherein



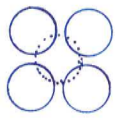
can exhibit



SIMPLE packing,



FACE-CENTERED packing, (a.k.a. ccp)



BODY-CENTERED packing.

ELECTRICAL CONDUCTIVITY

INSULATORS

$(4, +\infty)$ -eV E_g ; large Δx ;

$((\gg 20), (\gg 7)) - (\Omega \text{cm})^{-1} \sigma$

Empty conduction band w/ all e^- in the valence band @ 0K.

SEMICONDUCTORS

$[1, 4]$ -eV E_g ; small Δx ;

$((\gg 7), (\ll 2)) - (\Omega \text{cm})^{-1} \sigma$

Can be either intrinsic / pure (e.g. GaAs) or extrinsic / doped (e.g. $\text{SnO}_2 : \text{F}$); e^- behavior is quite diverse (see right).

METALS $[0, 1)$ -eV E_g ;

zero Δx ;

$((\ll 2), (\ll 8)) - (\Omega \text{cm})^{-1} \sigma$

e^- s spread btwn valence and conduction bands; σ near 0K. (superconductivity)

The unit cells, in combination with various packing arrangements, yield

the fourteen BRAVAIS LATTICE structures.

Ruling out thermodynamically unfavorable* configurations results in the

CRYSTAL STRUCTURE TYPES

(UNARY: Diamond (ZnS -esque) + Most metals.);

(BINARY: (1:2: CaF_2 Fluorite 50 cubic CN 4:8;

CdI_2 50 Oh-hep CN 3:6;

CdCl_2 50 Oh-ccp CN 3:6);

(1:1: (cubic (.733, 1) : CsCl 100 cubic CN 8:8);

(Oh (.414, .732) : NiAs 100 hep CN 6:6;

NaCl Rock Salt 100 ccp CN 6:6);

(Td (.225, .414) : ZnS Wurtzite 50 hep CN 4:4;

ZnS Zinc Blende 50 ccp CN 4:4));

(2:1: (Td : [Does Not Exist] 100 hep CN 8:4;

Antifluorite 100 ccp CN 8:4));

(TERNARY: ABO_3 Perovskite 25 Oh cubic;

AB_2O_4 Spinel 50 Oh 12.5 Td ccp;

AB_2O_4 Spinel 25 Oh 12.5 Td 25 Oh ccp)

* via the Born-Mayer equation.

a comparison of: semiconductors.

N-TYPE vs. P-TYPE

Reduction yields...

C.B. H.B.

N type

eg. $\text{Sn} : \text{In}_2\text{O}_3$
 $\text{Si} : \text{P}$

Oxidation yields...

C.B. H.B.

P type

eg. $\text{In} : \text{SnO}_2$
 $\text{Si} : \text{Al}$

Some common E_g s in eV:

α -Sn < 0.1

Ge 0.66

Si 1.1

GaAs 1.42

ZnSe 2.7

CuBr 2.9

C 5.5